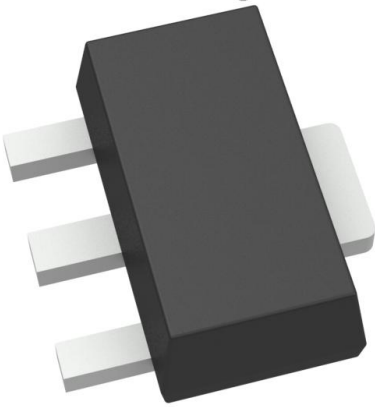


# 2DB1132P-13 Datasheet

[www.digi-electronics.com](http://www.digi-electronics.com)



<https://www.DiGi-Electronics.com>

|                              |                                                                         |
|------------------------------|-------------------------------------------------------------------------|
| DiGi Electronics Part Number | 2DB1132P-13-DG                                                          |
| Manufacturer                 | <a href="#">Diodes Incorporated</a>                                     |
| Manufacturer Product Number  | 2DB1132P-13                                                             |
| Description                  | TRANS PNP 32V 1A SOT89-3                                                |
| Detailed Description         | Bipolar (BJT) Transistor PNP 32 V 1 A 190MHz 1 W Surface Mount SOT-89-3 |



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

DiGi is a global authorized distributor of electronic components.

## Purchase and inquiry

Manufacturer Product Number:

2DB1132P-13

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

32 V

Current - Collector Cutoff (Max):

500nA (ICBO)

Power - Max:

1 W

Operating Temperature:

-55°C ~ 150°C (TJ)

Package / Case:

TO-243AA

Base Product Number:

2DB1132

Manufacturer:

Diodes Incorporated

Product Status:

Obsolete

Current - Collector (Ic) (Max):

1 A

Vce Saturation (Max) @ Ib, Ic:

500mV @ 50mA, 500mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

82 @ 100mA, 3V

Frequency - Transition:

190MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-89-3

## Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99





2DB1132P/Q/R

32V PNP POWER SWITCHING TRANSISTOR IN SOT89

## Features

- $BV_{CE0} > -32V$
- $I_C = -1A$  High Continuous Collector Current
- Complementary NPN Type: 2DD1664
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at <https://www.diodes.com/products/automotive/automotive-products/>.**
- **This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. <https://www.diodes.com/quality/product-definitions/>**

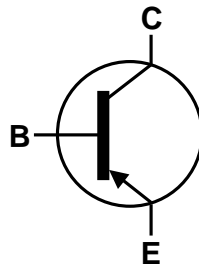
## Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.055 grams (Approximate)

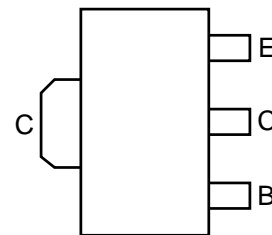
SOT89



Top View



Device Symbol

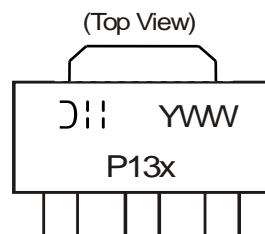
Pin Out  
Top View

## Ordering Information (Note 4)

| Part Number  | Status   | Marking Code | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|--------------|----------|--------------|--------------------|-----------------|-------------------|
| 2DB1132P-13  | Obsolete | P13P         | 13                 | 12              | 2,500             |
| 2DB1132Q-13  | Obsolete | P13Q         | 13                 | 12              | 2,500             |
| 2DB1132R-13  | Active   | P13R         | 13                 | 12              | 2,500             |
| 2DB1132R-13R | Active   | P13R         | 13                 | 12              | 4,000             |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



DII = Manufacturer's Marking  
 P13x = Product Type Marking Code:  
     Where P13P = 2DB1132P  
           P13Q = 2DB1132Q  
           P13R = 2DB1132R  
 YWW = Date Code Marking  
 Y = Last Digit of Year (ex: 1 = 2021)  
 WW = Week Code (01 to 52)



2DB1132P/Q/R

**Absolute Maximum Ratings** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

| Characteristic               | Symbol    | Value | Unit |
|------------------------------|-----------|-------|------|
| Collector-Base Voltage       | $V_{CB0}$ | -40   | V    |
| Collector-Emitter Voltage    | $V_{CE0}$ | -32   | V    |
| Emitter-Base Voltage         | $V_{EB0}$ | -5    | V    |
| Continuous Collector Current | $I_C$     | -1    | A    |
| Peak Pulse Current           | $I_{CM}$  | -2    | A    |

**Thermal Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

| Characteristic                              |          | Symbol          | Value       | Unit               |
|---------------------------------------------|----------|-----------------|-------------|--------------------|
| Power Dissipation                           | (Note 5) | $P_D$           | 1           | W                  |
|                                             | (Note 6) |                 | 1.5         |                    |
|                                             | (Note 7) |                 | 2           |                    |
| Thermal Resistance, Junction to Ambient Air | (Note 5) | $R_{\theta JA}$ | 125         | $^\circ\text{C/W}$ |
|                                             | (Note 6) |                 | 83          |                    |
|                                             | (Note 7) |                 | 60          |                    |
| Thermal Resistance, Junction to Case        | (Note 5) | $R_{\theta JC}$ | 18          | $^\circ\text{C/W}$ |
| Thermal Resistance, Junction to Lead        | (Note 8) | $R_{\theta JL}$ | 22          | $^\circ\text{C/W}$ |
| Operating and Storage Temperature Range     |          | $T_J, T_{STG}$  | -55 to +150 | $^\circ\text{C}$   |

**ESD Ratings** (Note 9)

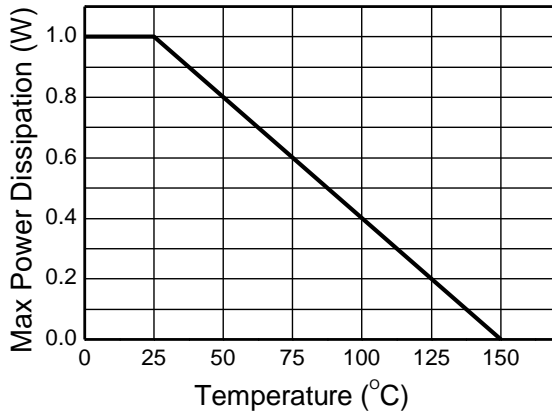
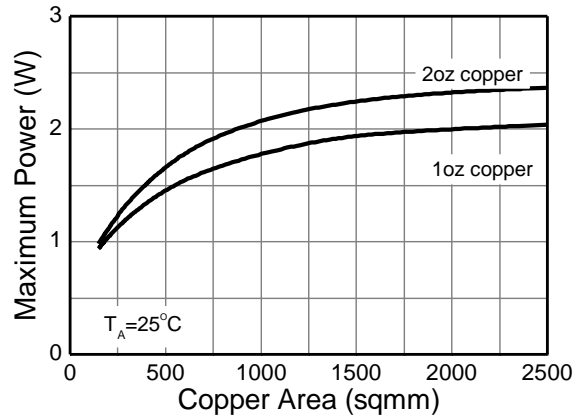
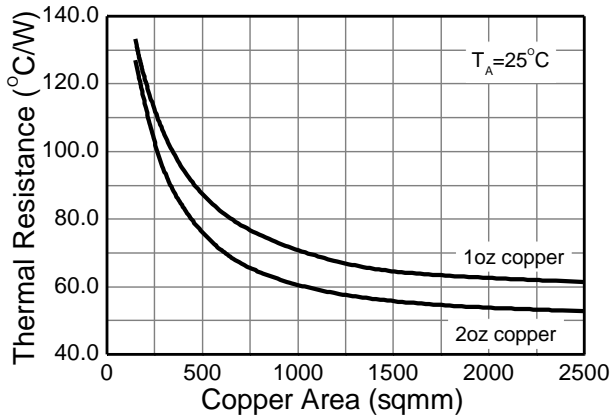
| Characteristic                             | Symbol  | Value | Unit | JEDEC Class |
|--------------------------------------------|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V    | 3A          |
| Electrostatic Discharge - Machine Model    | ESD MM  | 400   | V    | C           |

- Notes:
- For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  - Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.
  - Same as note (5), except the device is mounted on 50mm x 50mm 1oz copper.
  - Thermal resistance from junction to solder-point (on the exposed collector pad).
  - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

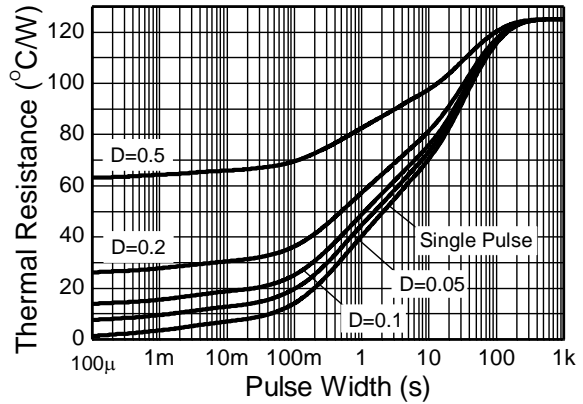


2DB1132P/Q/R

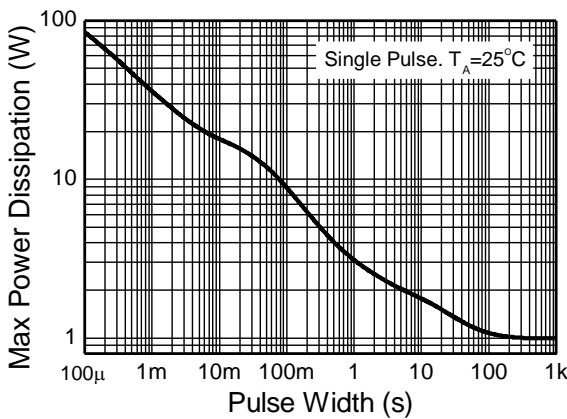
**Thermal Characteristics and Derating Information**



**Derating Curve**



**Transient Thermal Impedance**



**Pulse Power Dissipation**



**2DB1132P/Q/R**

**Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

| Characteristic                                  | Symbol                           | Min      | Typ  | Max  | Unit          | Test Condition                                                    |                                               |
|-------------------------------------------------|----------------------------------|----------|------|------|---------------|-------------------------------------------------------------------|-----------------------------------------------|
| Collector-Base Breakdown Voltage                | $BV_{CBO}$                       | -40      | —    | —    | V             | $I_C = -50\mu\text{A}$                                            |                                               |
| Collector-Emitter Breakdown Voltage (Note 10)   | $BV_{CEO}$                       | -32      | —    | —    | V             | $I_C = -1\text{mA}$                                               |                                               |
| Emitter-Base Breakdown Voltage                  | $BV_{EBO}$                       | -5       | —    | —    | V             | $I_E = -50\mu\text{A}$                                            |                                               |
| Collector Cut-Off Current                       | $I_{CBO}$                        | —        | —    | -0.5 | $\mu\text{A}$ | $V_{CB} = -20\text{V}$                                            |                                               |
| Emitter Cut-Off Current                         | $I_{EBO}$                        | —        | —    | -0.5 | $\mu\text{A}$ | $V_{EB} = -4\text{V}$                                             |                                               |
| Static Forward Current Transfer Ratio (Note 10) | 2DB1132P<br>2DB1132Q<br>2DB1132R | $h_{FE}$ | 82   | —    | 180           | —                                                                 | $I_C = -100\text{mA}$ , $V_{CE} = -3\text{V}$ |
|                                                 |                                  |          | 120  |      | 270           |                                                                   |                                               |
|                                                 |                                  |          | 180  |      | 390           |                                                                   |                                               |
| Collector-Emitter Saturation Voltage (Note 10)  | $V_{CE(sat)}$                    | —        | -125 | -500 | mV            | $I_C = -500\text{mA}$ , $I_B = -50\text{mA}$                      |                                               |
| Transition Frequency                            | $f_T$                            | —        | 190  | —    | MHz           | $I_E = -50\text{mA}$ , $V_{CE} = -5\text{V}$ , $f = 30\text{MHz}$ |                                               |
| Output Capacitance                              | $C_{obo}$                        | —        | 12   | 30   | pF            | $I_E = 0\text{A}$ , $V_{CB} = -10\text{V}$ , $f = 1\text{MHz}$    |                                               |

Note: 10. Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ . Duty cycle  $\leq 2\%$ .

**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

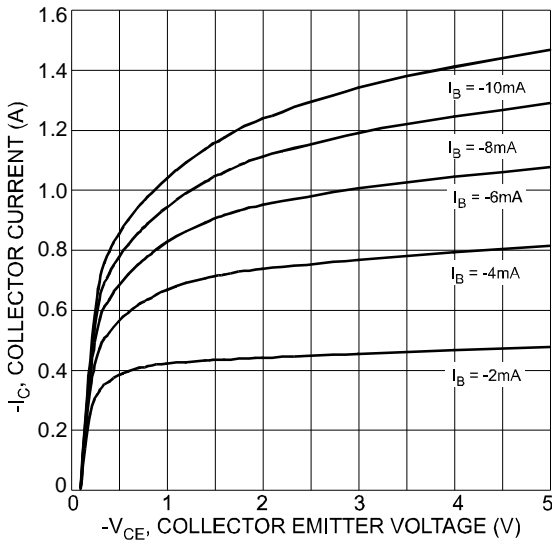


Fig. 1 Typical Collector Current vs. Collector-Emitter Voltage

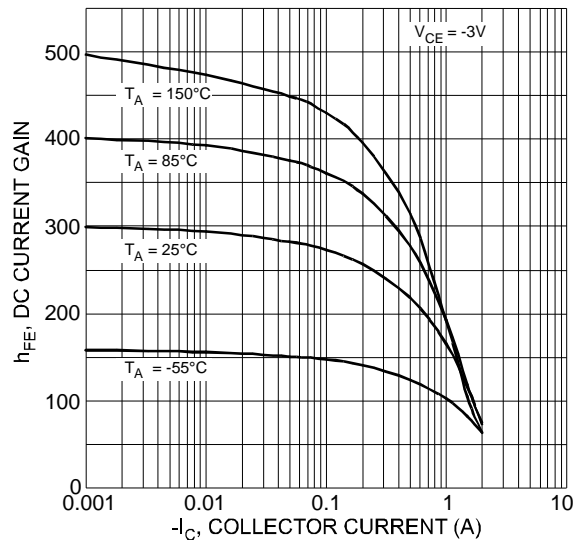


Fig. 2 Typical DC Current Gain vs. Collector Current (2DB1132R)

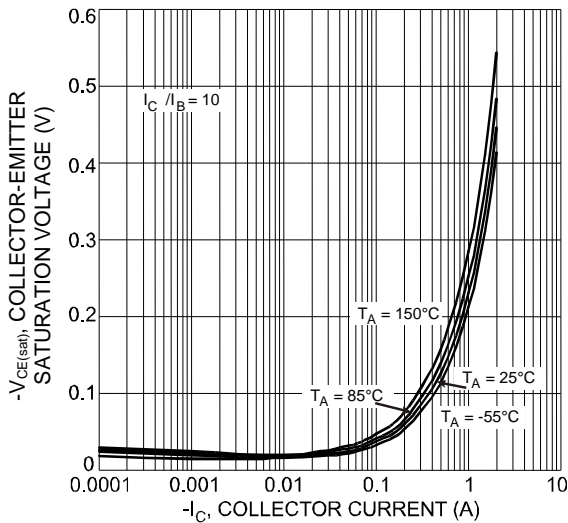


Fig. 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

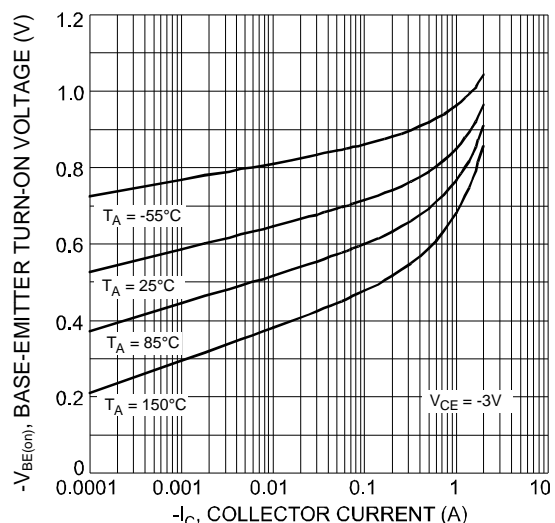


Fig. 4 Typical Base-Emitter Turn-On Voltage vs. Collector Current



2DB1132P/Q/R

**Typical Electrical Characteristics** (continued) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

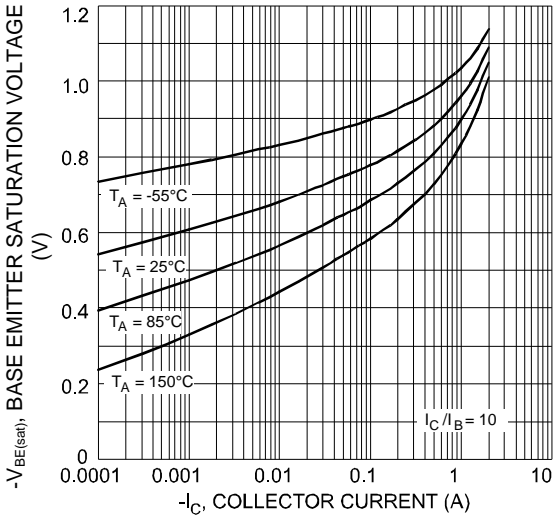


Fig. 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

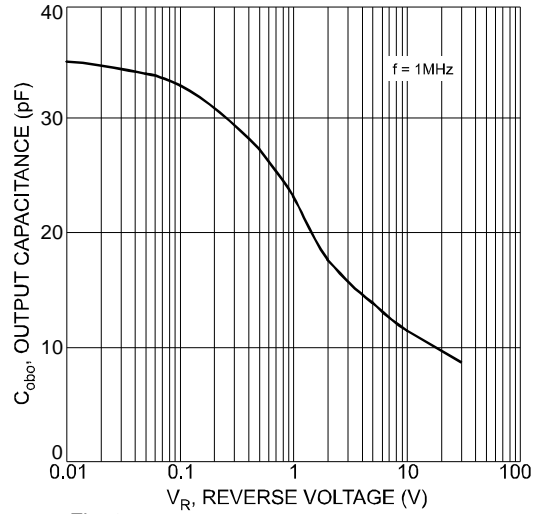


Fig. 6 Typical Output Capacitance Characteristics

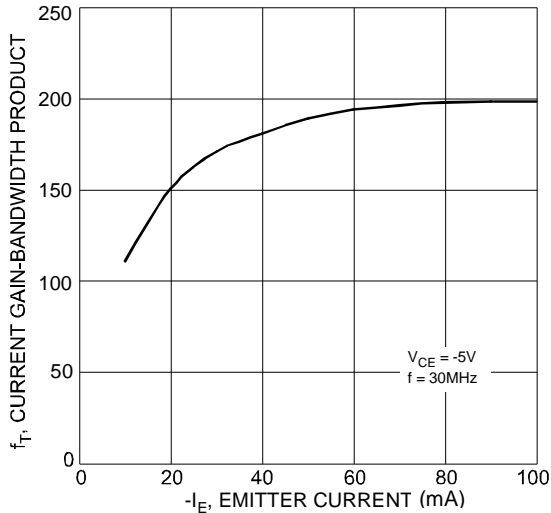
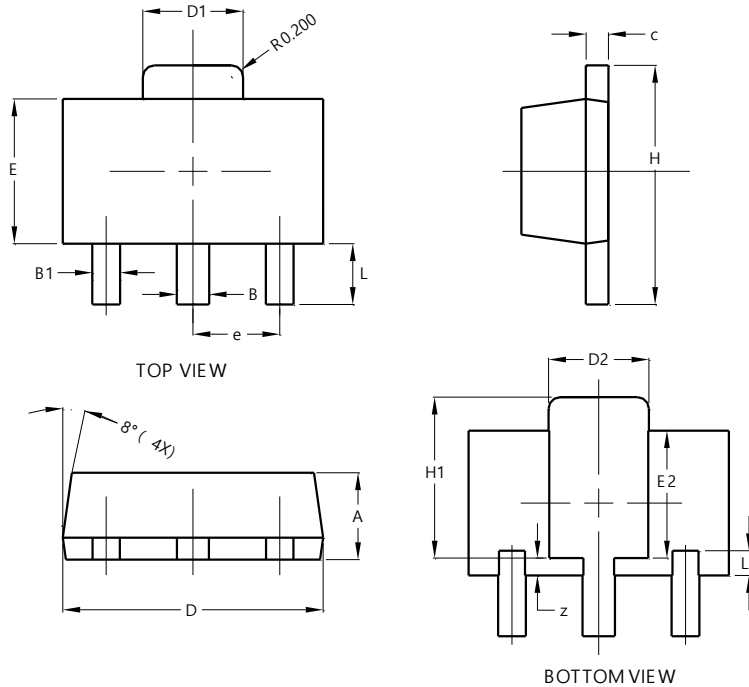


Fig. 7 Typical Gain-Bandwidth Product vs. Emitter Current

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### SOT89

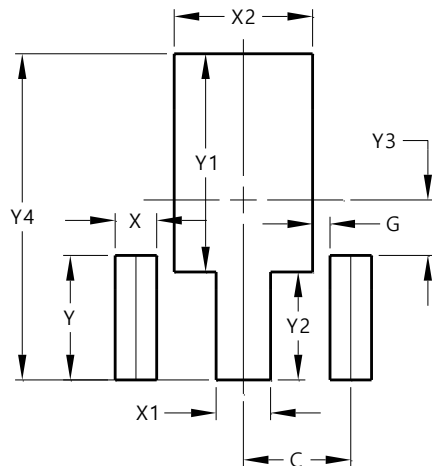


| SOT89                |       |       |       |
|----------------------|-------|-------|-------|
| Dim                  | Min   | Max   | Typ   |
| A                    | 1.40  | 1.60  | 1.50  |
| B                    | 0.50  | 0.62  | 0.56  |
| B1                   | 0.42  | 0.54  | 0.48  |
| c                    | 0.35  | 0.43  | 0.38  |
| D                    | 4.40  | 4.60  | 4.50  |
| D1                   | 1.62  | 1.83  | 1.733 |
| D2                   | 1.61  | 1.81  | 1.71  |
| E                    | 2.40  | 2.60  | 2.50  |
| E2                   | 2.05  | 2.35  | 2.20  |
| e                    | -     | -     | 1.50  |
| H                    | 3.95  | 4.25  | 4.10  |
| H1                   | 2.63  | 2.93  | 2.78  |
| L                    | 0.90  | 1.20  | 1.05  |
| L1                   | 0.327 | 0.527 | 0.427 |
| z                    | 0.20  | 0.40  | 0.30  |
| All Dimensions in mm |       |       |       |

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### SOT89



| Dimensions | Value (in mm) |
|------------|---------------|
| C          | 1.500         |
| G          | 0.244         |
| X          | 0.580         |
| X1         | 0.760         |
| X2         | 1.933         |
| Y          | 1.730         |
| Y1         | 3.030         |
| Y2         | 1.500         |
| Y3         | 0.770         |
| Y4         | 4.530         |



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